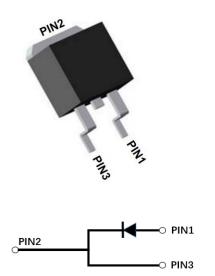


# YJD112010BGHQ



# **Silicon Carbide Schottky Diode**

V <sub>RRM</sub>	1200V
I <sub>F (135°C)</sub>	15A
Q <sub>C</sub>	58nC



#### **Features**

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- AEC-Q101 qualified
- High-frequency operation
- Reduction of EMI

### **Typical Applications**

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

#### **Mechanical Data**

• Package: TO-263

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free

• Terminals: Tin plated leads

• Polarity: As marked

### ■Maximum Ratings (T<sub>C</sub>=25°C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D112010BGH
Reverse voltage (Repetitive peak) @ T <sub>j</sub> =25°C	$V_{RRM}$	٧	1200
Reverse voltage (Surge peak) @ T <sub>j</sub> =25°C	$V_{RSM}$	V	1200
Reverse voltage (DC) @ T <sub>j</sub> =25°C	$V_{DC}$	V	1200
Continuous forward current @ T <sub>C</sub> =25°C			31.5
Continuous forward current @ T <sub>C</sub> =135°C	I <sub>F</sub>	А	15
Continuous forward current @ T <sub>C</sub> =155°C			10
Non-repetitive peak forward surge current @ T <sub>C</sub> =25°C, tp=10ms, Half Sine Wave	I <sub>FSM</sub>	А	90
Power Dissipation@ T <sub>C</sub> =25°C	D	W	153
Power Dissipation@ T <sub>C</sub> =110°C	P <sub>TOT</sub>		66
i²t Value@ T <sub>C</sub> =25°C ,tp=10ms	∫ i²dt	A <sup>2</sup> S	40.5
Operating junction and Storage temperature range	$T_{j}$ , $T_{stg}$	°C	-55 to +175





#### **■**Electrical Characteristics

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drop	V <sub>F</sub>	V	I <sub>F</sub> =10A, T <sub>j</sub> =25°C	1.38	1.55
			I <sub>F</sub> =10A, T <sub>j</sub> =175°C	2	-
Reverse leakage current	I <sub>R</sub>	μΑ	V <sub>R</sub> =1200V, T <sub>j</sub> =25°C	0.5	20
			V <sub>R</sub> =1200V, T <sub>j</sub> =175°C	8	-
Total capacitive charge	Q <sub>C</sub>	nC	$V_R$ =800V, $T_j$ =25°C , $Q_C$ = $\int_0^{VR} C(V) dV$	58	-
Total capacitance	С	pF	V <sub>R</sub> =0V, f=1MHZ	813	-
			V <sub>R</sub> =400V, f=1MHZ	54	-
			V <sub>R</sub> =800V, f=1MHZ	40	-
Capacitance Stored Energy	Ec	μJ	V <sub>R</sub> =800V	15	-

## **■Thermal Characteristics** $(T_a=25$ $^{\circ}$ C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	R <sub>eJ-C</sub>	°C W	0.98

## **■**Typical Characteristics

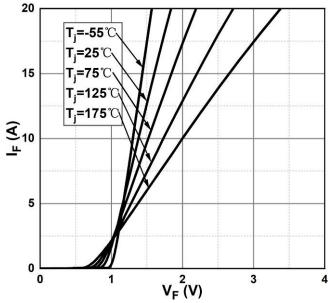


Figure 1. Forward Characteristics

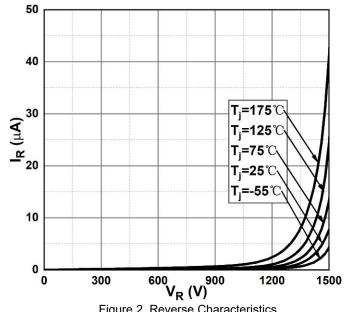
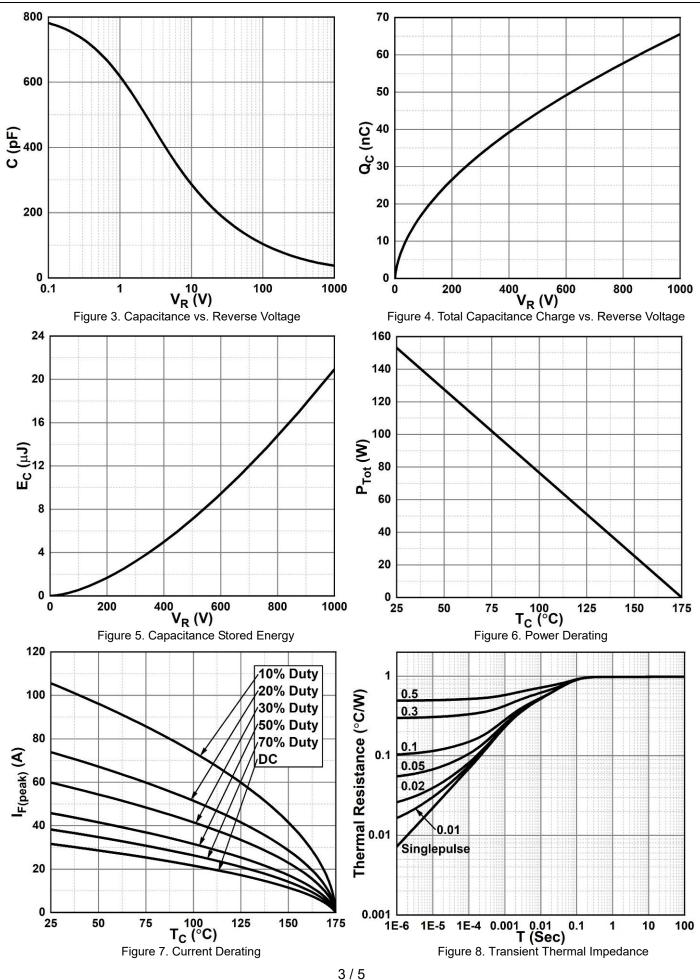


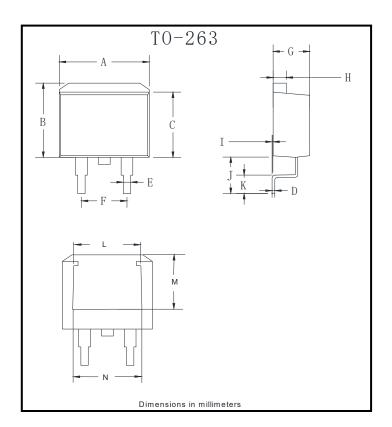
Figure 2. Reverse Characteristics







### **■**Outline Dimensions



TO-263				
Dim	Min	Max		
Α	9.5	11.5		
В	9.7	10.5		
С	8.4	9.0		
D	0.28	0.64		
Е	0.68	0.94		
F	4.55	5.6		
G	4.04	5.10		
Н	1.14	1.4		
Ι	0	0.2		
J	4.9	6.05		
K	1.79	2.79		
L	7.3	7.9		
М	6.2	6.8		
N	7.6	8.2		



### YJD112010BGHQ



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